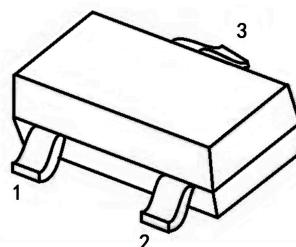


30V N-Channel Mosfet

FEATURES

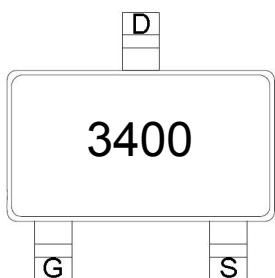
- $R_{DS(ON)} \leq 33m\Omega$ (21m Ω Typ.) @ $V_{GS}=10V$
- $R_{DS(ON)} \leq 39m\Omega$ (25m Ω Typ.) @ $V_{GS}=4.5V$
- $R_{DS(ON)} \leq 60m\Omega$ (36m Ω Typ.) @ $V_{GS}=2.5V$

SOT-23

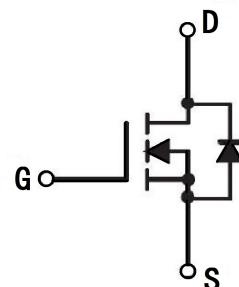
1. GATE
2. SOURCE
3. DRAIN

APPLICATIONS

- Load/Power Switching
- Interfacing Switching

MARKING

Other mark: "R0"

N-CHANNEL MOSFET**MAXIMUM RATINGS (Ta=25°C unless otherwise noted)**

Symbol	Parameter	Max.	Units
V_{DSS}	Drain-Source Voltage	30	V
V_{GSS}	Gate-Source Voltage	± 12	V
I_D	Continuous Drain Current	5.8	A
I_{DM}	Pulsed Drain Current ^{note1}	30	A
P_D	Power Dissipation	0.35	W
R_{eJA}	Thermal Resistance, Junction to Ambient	357	°C/W
T_J	Operating and Storage Temperature Range	150	°C
T_{STG}	Operating and Storage Temperature Range	-55 to +150	°C

MOSFET ELECTRICAL CHARACTERISTICS Ta=25 °C unless otherwise specified

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
Off Characteristics						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250µA	30	31.5	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 30V, V _{GS} = 0V, T _J = 25°C	-	-	1	µA
I _{GSS}	Gate to Body Leakage Current	V _{GS} = ±12V, V _{DS} = 0V	-	-	±100	nA
On Characteristics						
V _{G(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250µA	0.7	1	1.4	V
R _{DS(on)}	Static Drain-Source On-Resistance ^{note2}	V _{GS} = 10V, I _D = 5A	-	21	33	mΩ
		V _{GS} = 4.5V, I _D = 4A	-	25	39	
		V _{GS} = 2.5V, I _D = 3A	-	36	60	
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	-	-	1155	pF
C _{oss}	Output Capacitance		-	108	-	pF
C _{rss}	Reverse Transfer Capacitance		-	84	-	pF
Q _g	Total Gate Charge	V _{DS} = 15V, I _D = 5.8A, V _{GS} = 4.5V, f = 1.0MHz	-	10	-	nC
Q _{gs}	Gate-Source Charge		-	1.6	-	nC
Q _{gd}	Gate-Drain("Miller") Charge		-	3.1	-	nC
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{GS} = 10V, V _{DS} = 15V, R _L = 2.7Ω, R _{GEN} = 3Ω	-	-	5	ns
t _r	Turn-On Rise Time		-	-	7	ns
t _{d(off)}	Turn-Off Delay Time		-	-	40	ns
t _f	Turn-Off Fall Time		-	-	6	ns
Drain-Source Diode Characteristics and Maximum Ratings						
V _{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _{SD} = 1A, T _J = 25°C	-	0.8	1	V

Notes: 1. Pulse Test : Pulse Width < 300µs, Duty Cycle ≤2%.

2. Guaranteed by design, not subject to production testing.

TYPICAL PERFORMANCE CHARACTERISTICS

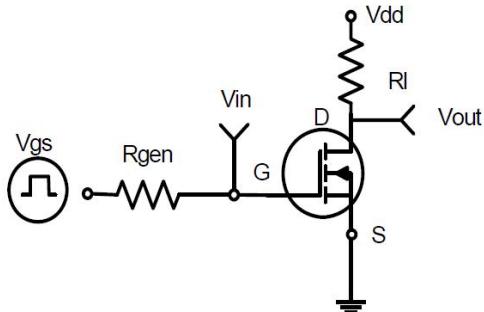


Figure 1:Switching Test Circuit

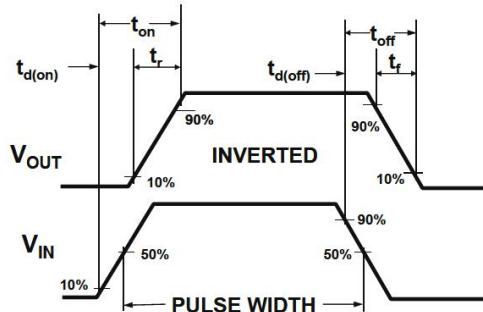


Figure 2:Switching Waveforms

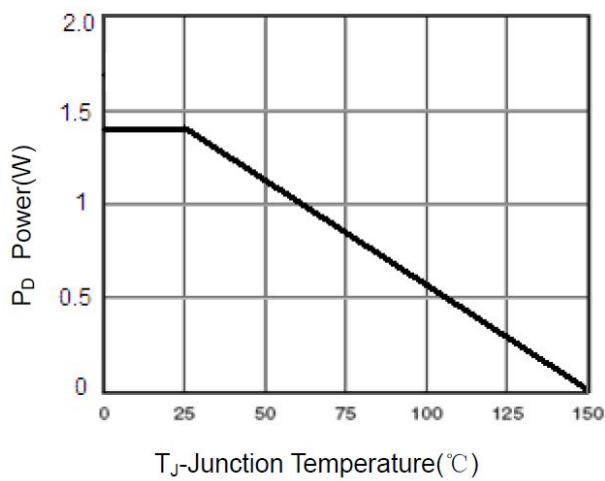


Figure 3 Power Dissipation

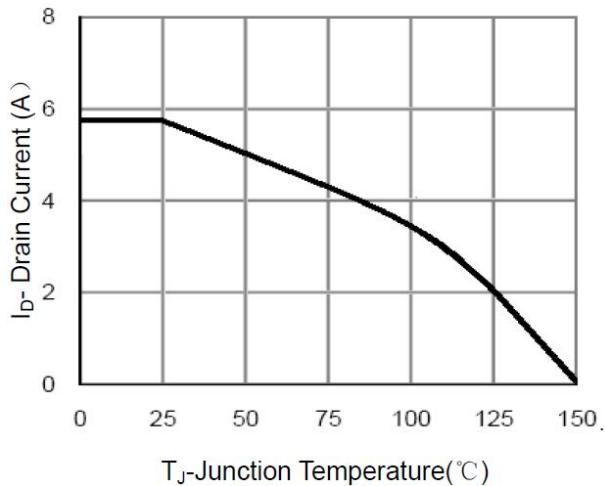


Figure 4 Drain Current

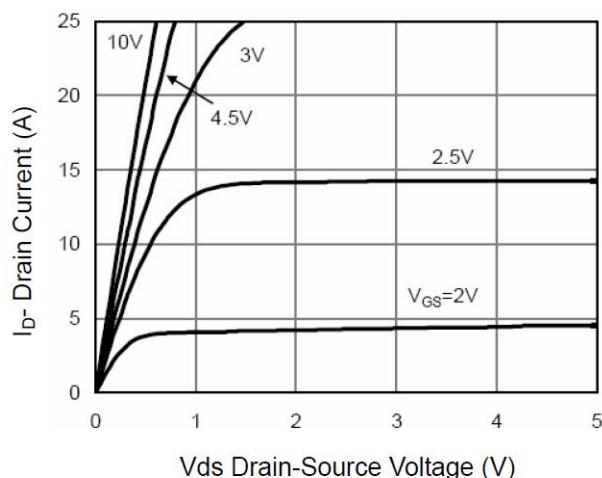


Figure 5 Output Characteristics

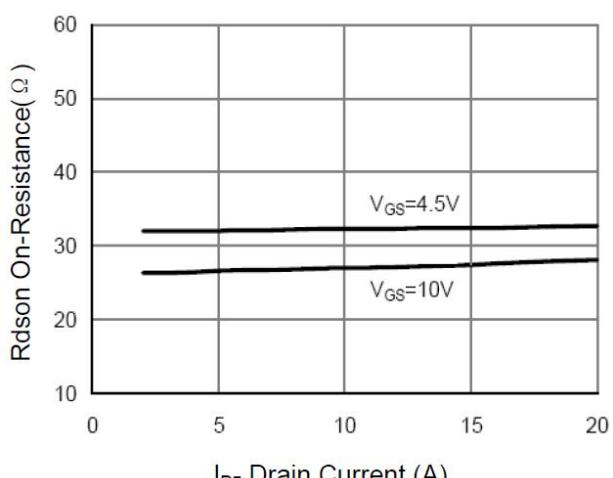
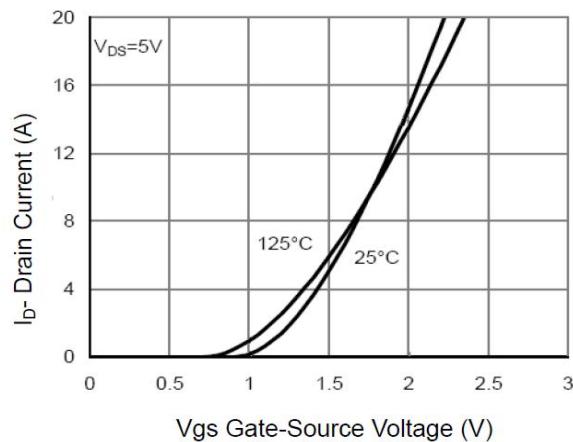
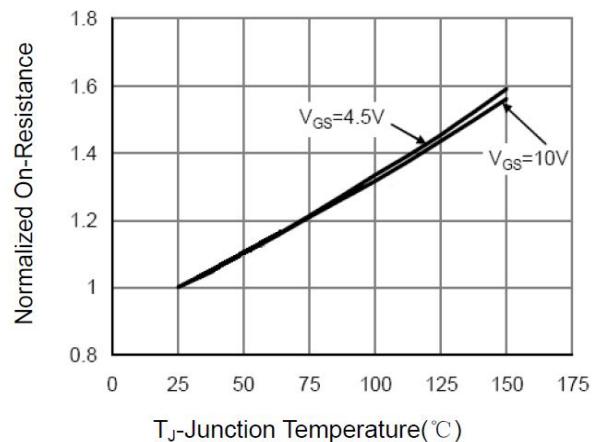
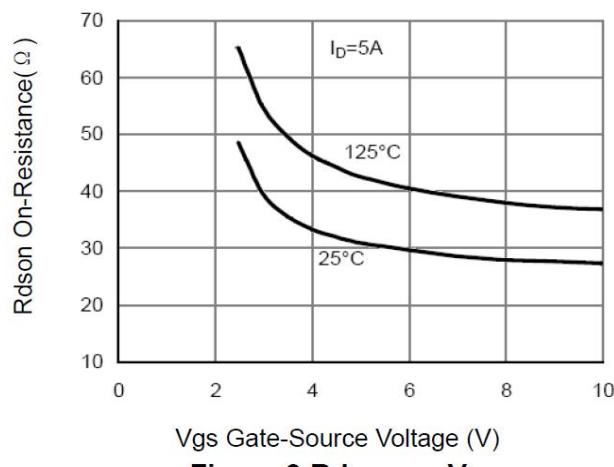
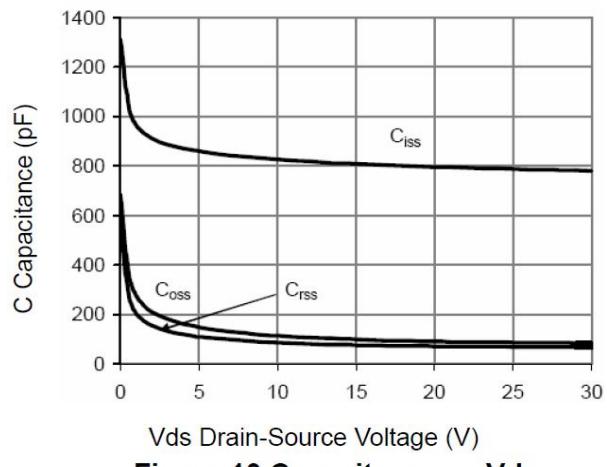
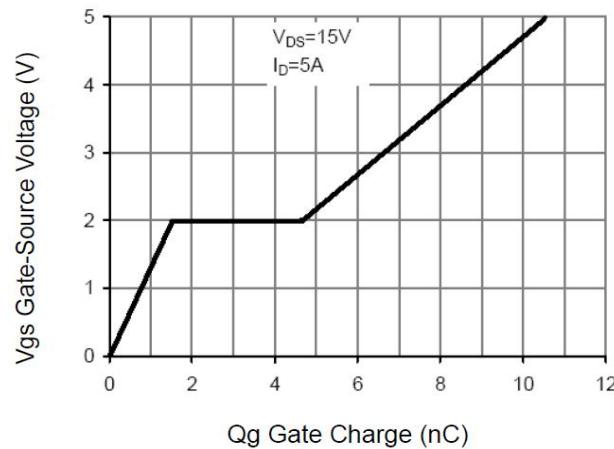
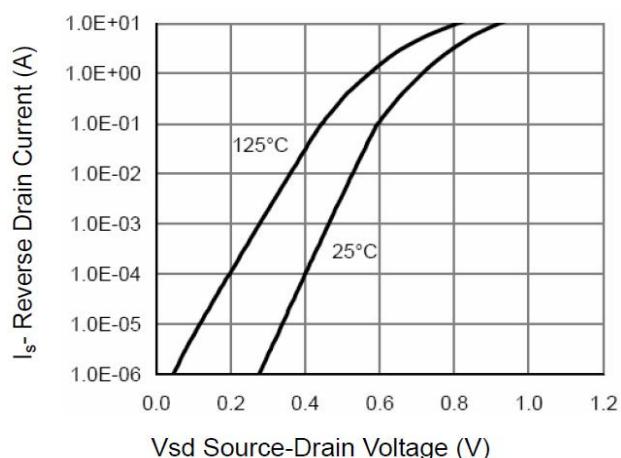
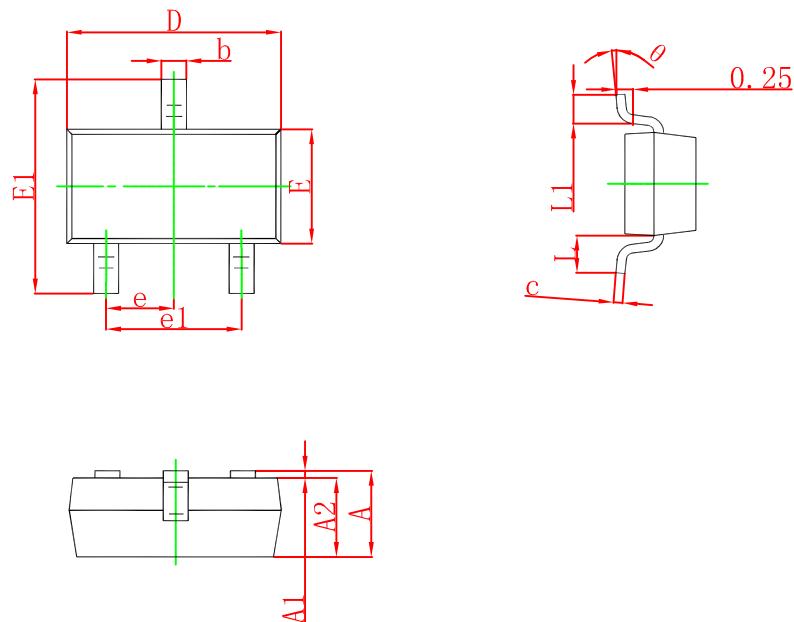


Figure 6 Drain-Source On-Resistance

TYPICAL PERFORMANCE CHARACTERISTICS (cont.)

**Figure 7 Transfer Characteristics****Figure 8 Drain-Source On-Resistance****Figure 9 $R_{DS(on)}$ vs V_{GS}** **Figure 10 Capacitance vs V_{DS}** **Figure 11 Gate Charge****Figure 12 Source-Drain Diode Forward**

SOT-23 PACKAGE OUTLINE DRAWING



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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